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STUDIES OF THE FIELD ASSISTED PHOTOEMISSION FROM NANOCRYSTALLINE DIAMOND AND DIAMOND FIELD EMITTER ARRAYS

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Los Alamos National Laboratory

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August 15th, 2018



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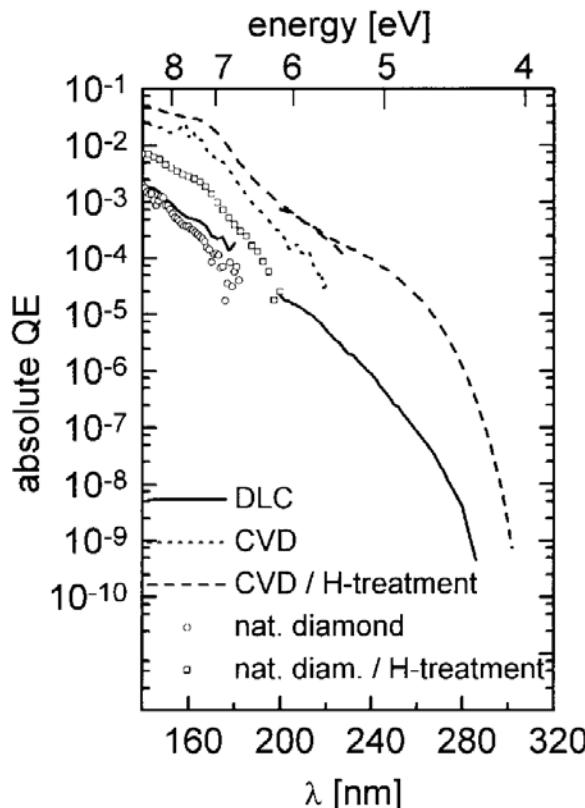
What type of electron source is needed for dielectric laser accelerators?

Field emission in DFEAs	Photoemission
<ul style="list-style-type: none">• 0.1 mA per 10 µm square• 100 A/cm²	<ul style="list-style-type: none">• UV laser 193 nm (6.4 eV), 200 mJ/pulse (20 ns).• Focus down to 5 mm x 5 mm.• 40 W in 10µm x 10µm ($4*10^{19}$ photons/s).• With QE $\sim 10^{-3}$ we get $4*10^{16}$ electrons/emitting surface/s, or• 3 mA per 10 µm square• $3*10^3$ A/cm²



Small and well defined emission spot
High current
Photo-gated source

Photoemission from flat diamond: our data in agreement with existing reports



A. Breskin, R. Chechik, E. Shefer,
et al., Appl. Phys. Lett. **70** (1997)
3446

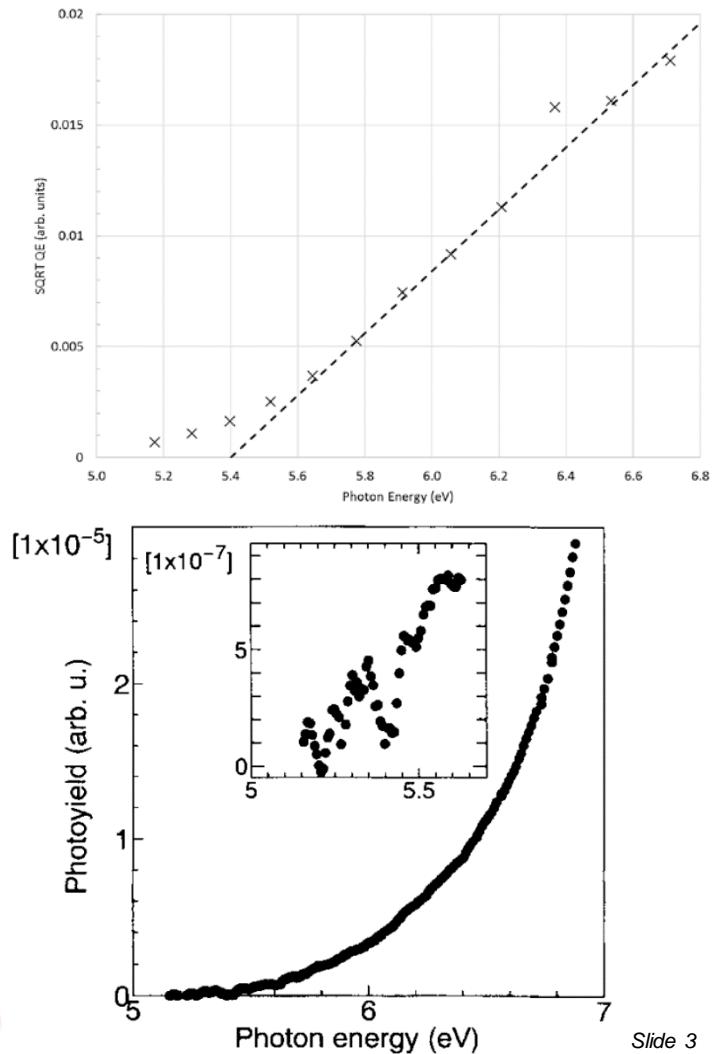


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N. Eimori, Y. Mori, A. Hatta,
T. Ito, A. Hiraki, Diamond &
Related Materials **4** (1995)
806



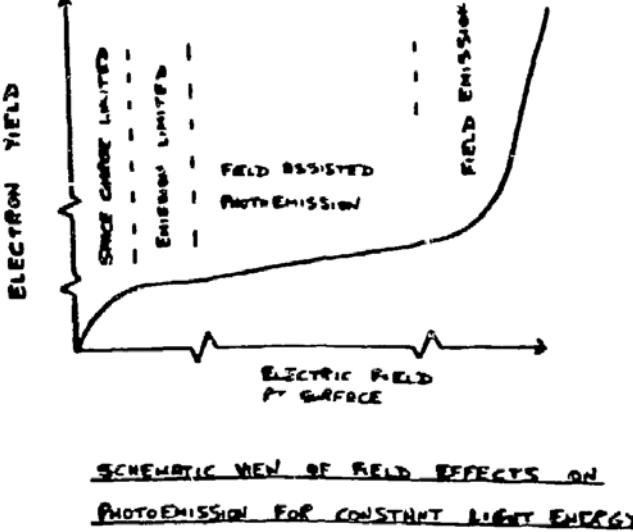
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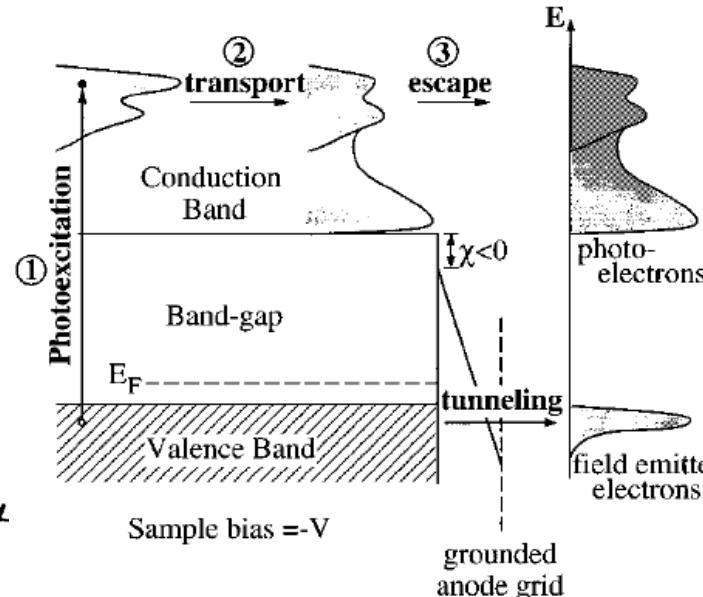
Slide 3



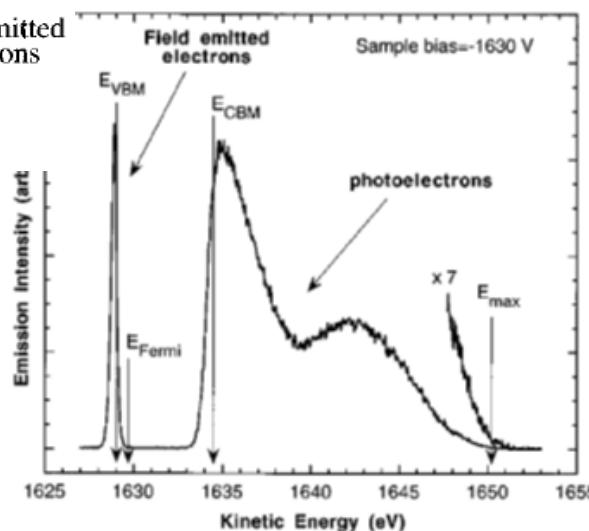
From Photoemission to Field Emission



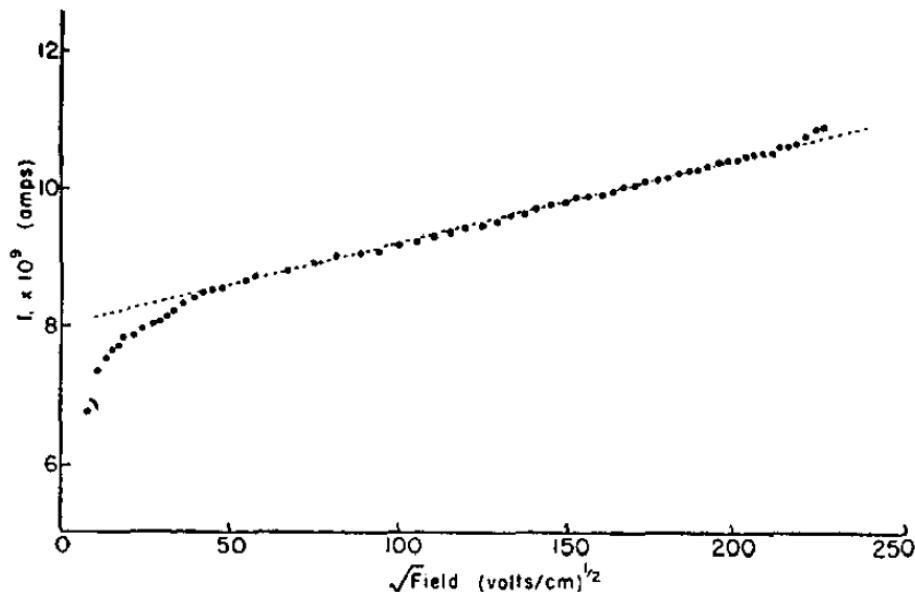
J. Fischer and T. Srinivasan-Rao, UV PHOTOEMISSION STUDIES OF METAL PHOTOCATHODES FOR PARTICLE ACCELERATORS, Fourth Workshop on Pulse Power Techniques for Future Accelerators, E. Maiorana Center, Erice, Italy, March 1988



C. Bandis and B. B. Pate, Simultaneous field emission and photoemission from diamond, Appl. Phys. Lett. **69** (3), 1996

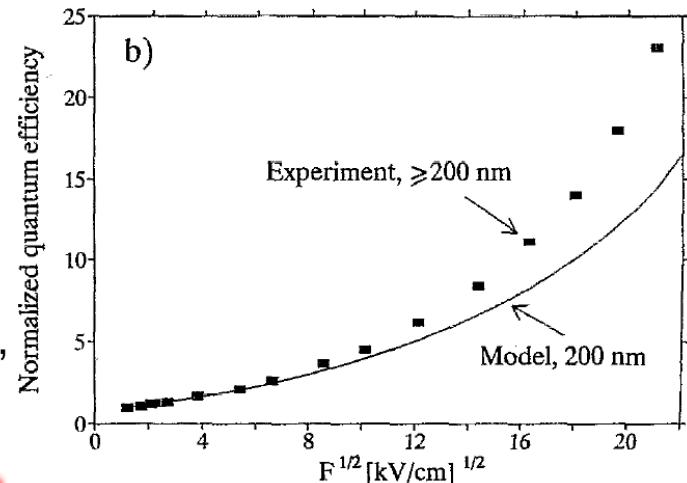
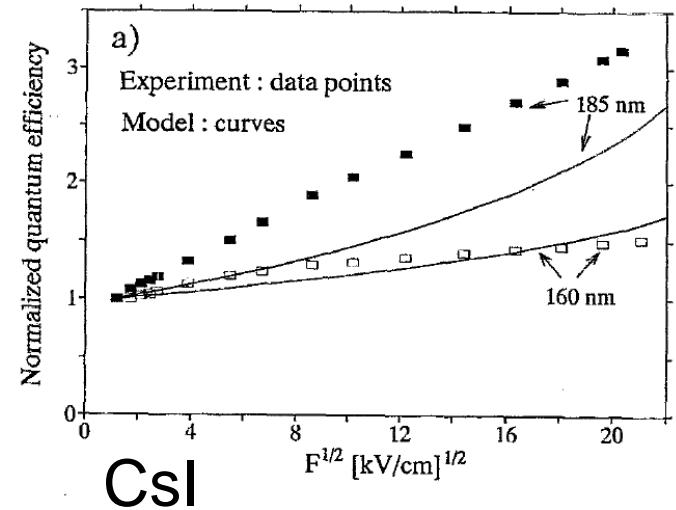


Field Assisted Photoemission: Metals & Semiconductors



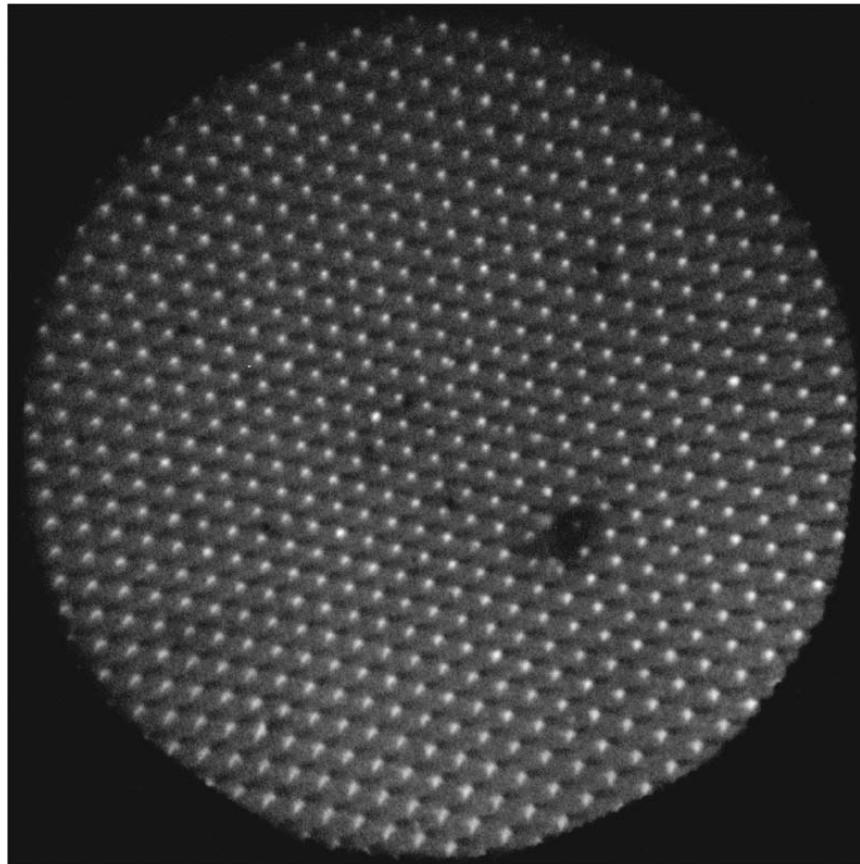
Photoelectric Schottky effect for polycrystalline tantalum

D. W. Juenker, Journal of Applied Physics **28** (1957)
1398



A. Buzulutskov, A. Breskin, and R. Chechik,
Journal of Applied Physics **77**, 2138 (1995)

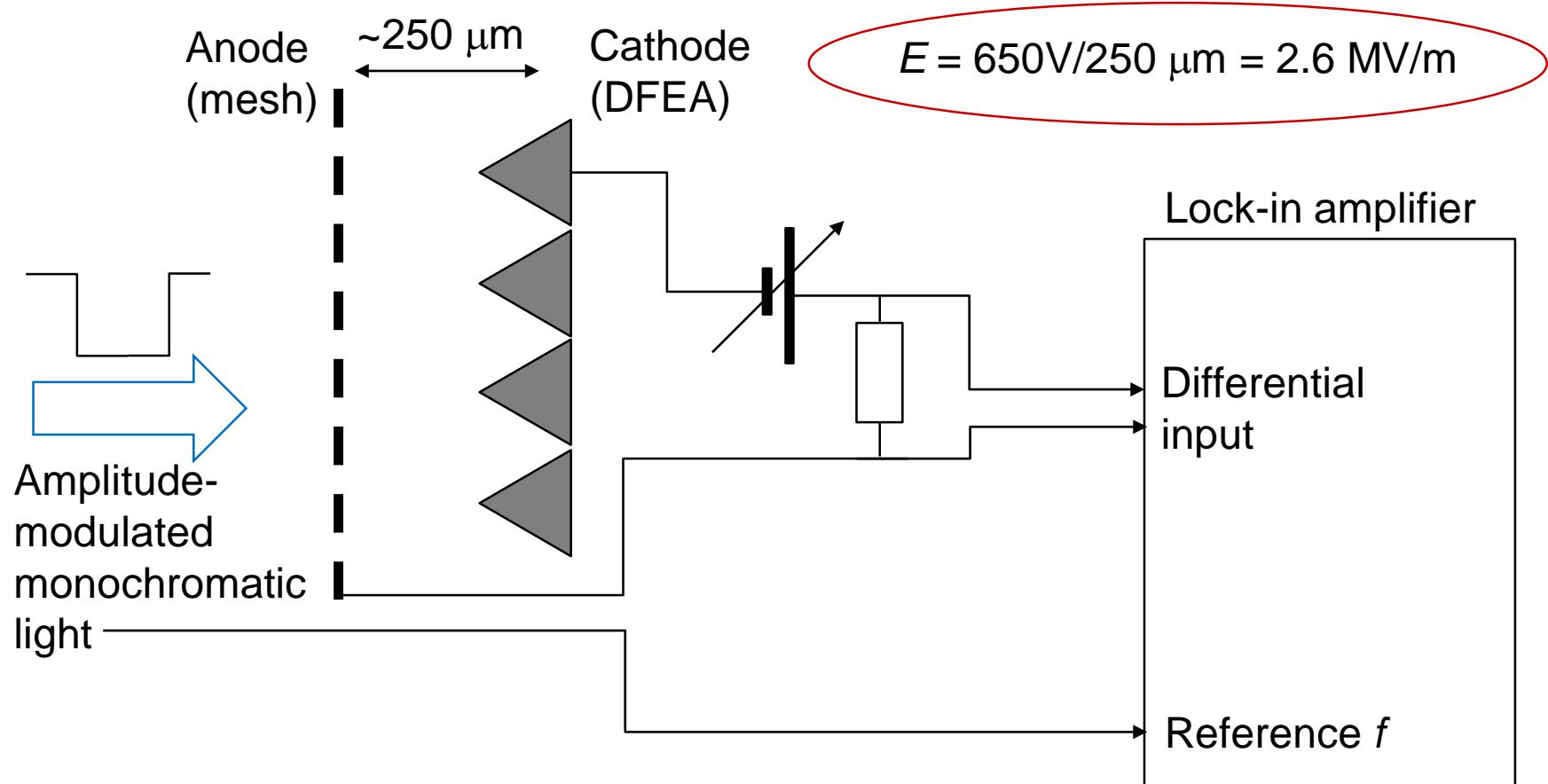
Field Assisted Photoemission from DFEA: existing studies



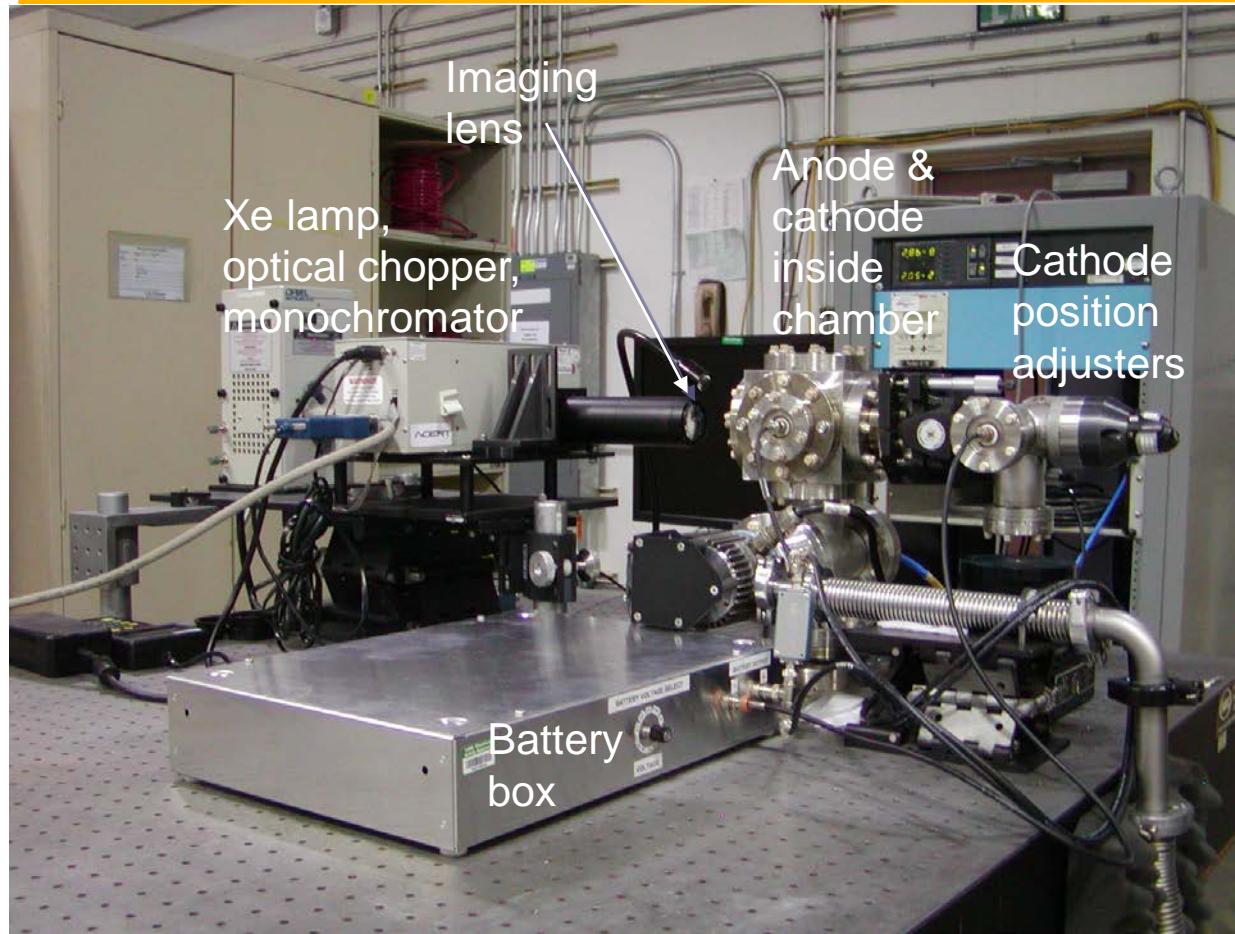
A PEEM image of the UNCD coated tip array at room temperature. Emission is evident from both the flat areas of the sample and the tipped structures.

J. M. Garguilo *et al.*, Thermionic field emission from nanocrystalline diamond-coated silicon tip arrays, Phys Rev B **72**, 165404 (2005)

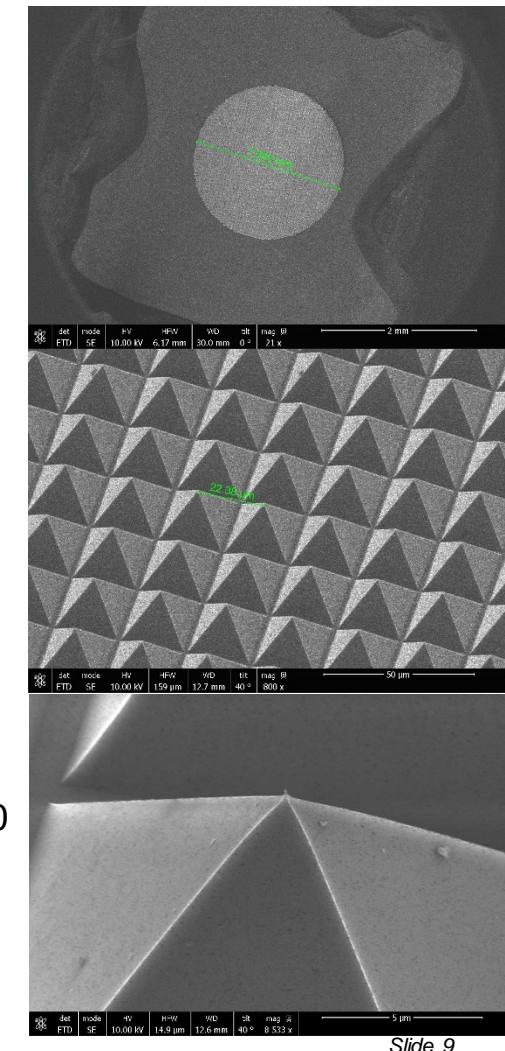
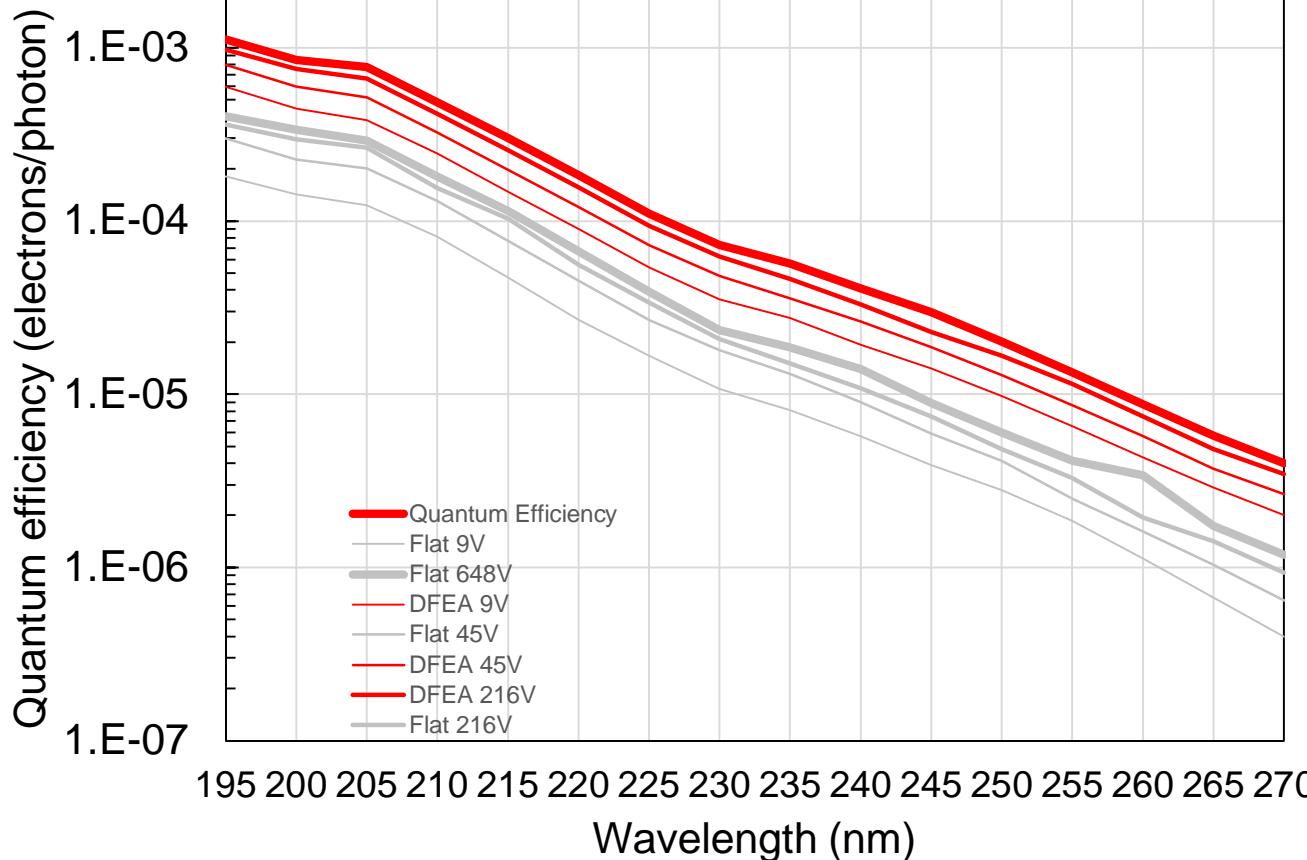
QE measurements scheme in electric fields up to ~3 MV/m



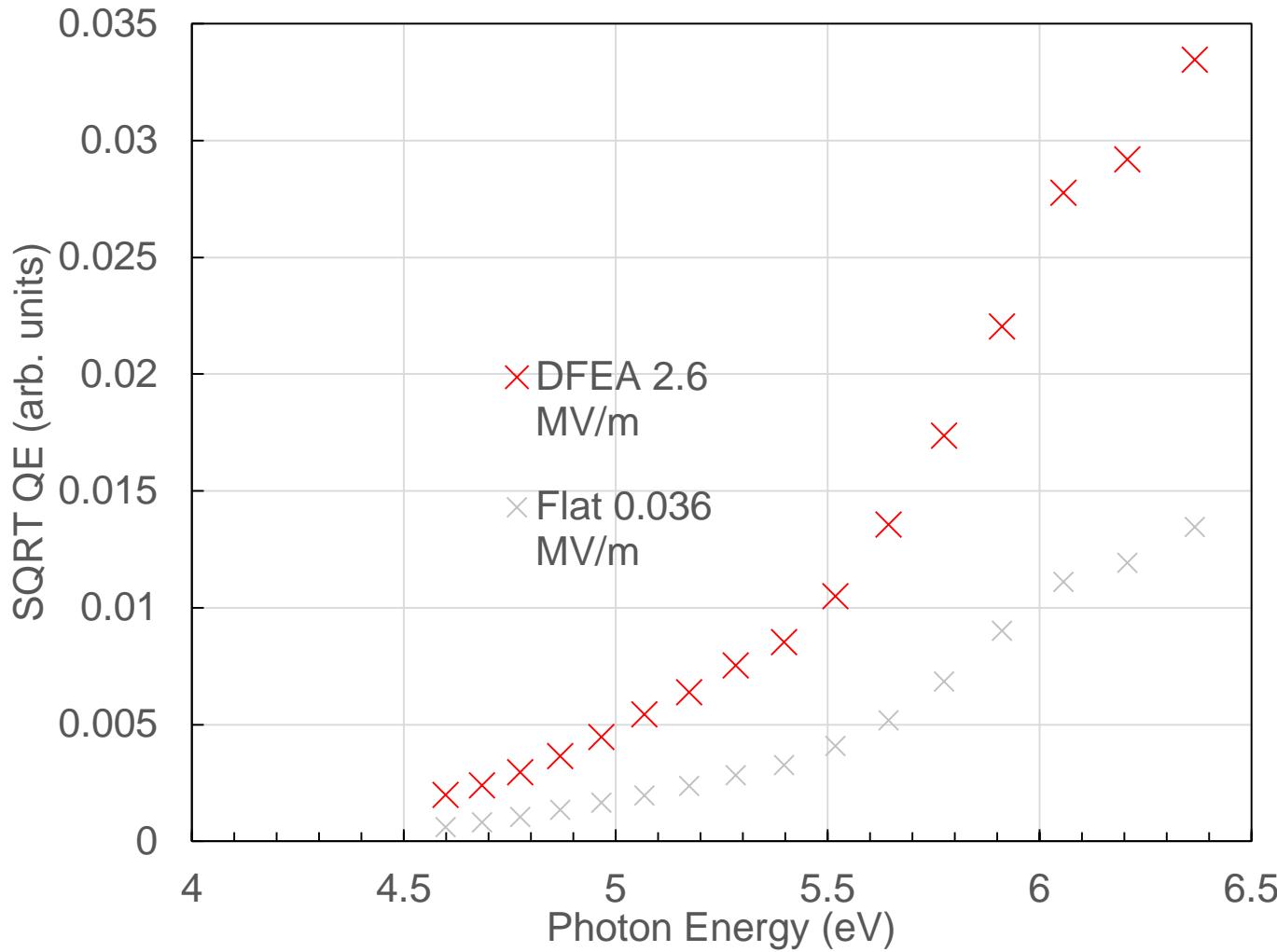
Field assisted photoemission setup



Measurements results: spectral response



Measurements results: photoemission threshold



Conclusions / Future Plans

- Experimental results indicate enhanced photoemission from relatively dense DFEAs, as compared to flat nanocrystalline diamond
- x3 enhancement of photoemission QE near the threshold in electric fields
~1 MV/m is observed in both flat and DFEA-patterned diamond samples, but the mechanism of enhancement is unclear
- Photoexcitation of individual tips with focused laser light is the next step to obtain quantitative QE data in high electric fields

Acknowledgements

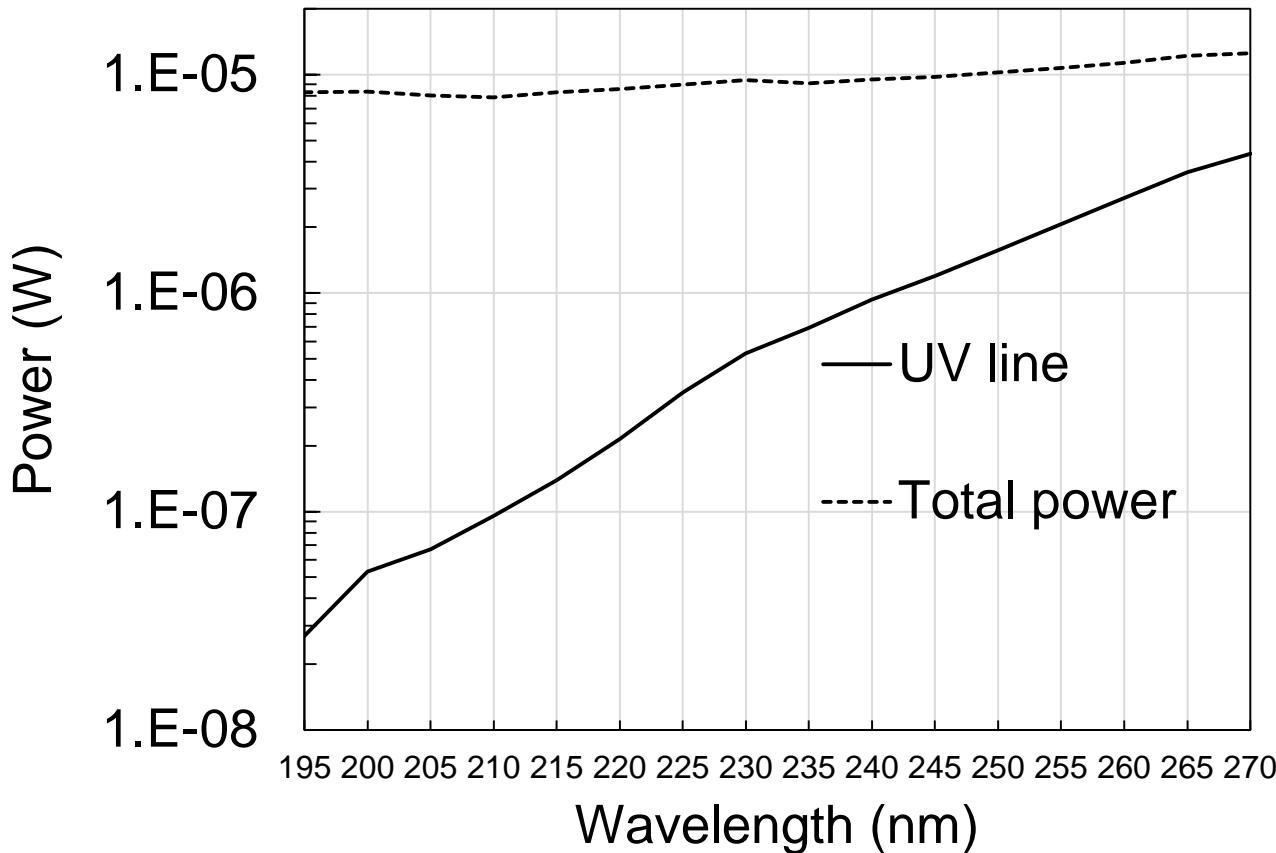
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- Fangze Liu: experiment automation
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- Mark Hoffbauer: precision mechanics

Related Presentations

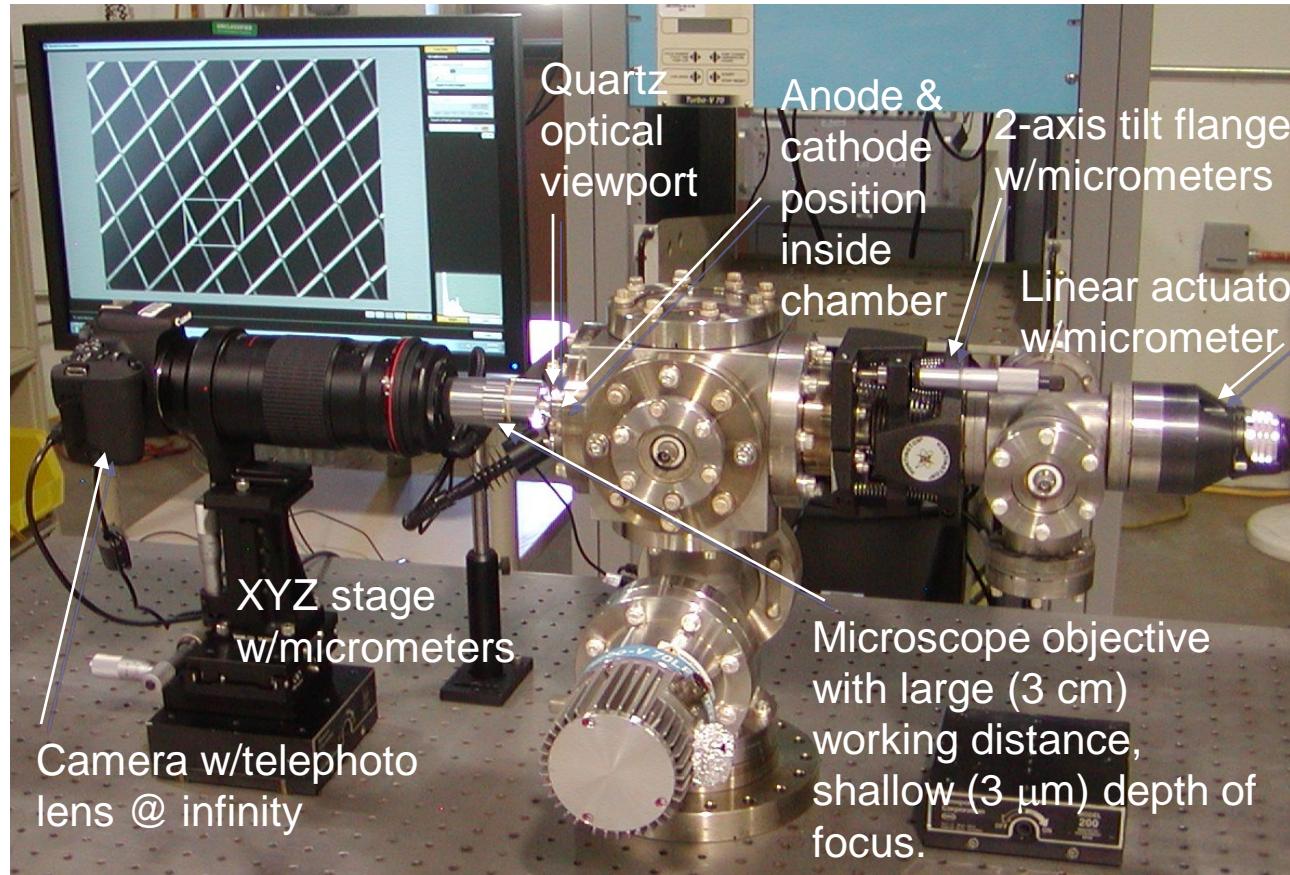
- Dongsung Kim *et al.*, "FABRICATION OF MICRON-SCALE DIAMOND FIELD EMITTER ARRAYS FOR DIELECTRIC LASER ACCELERATORS" - Poster (8/14, Tue)
- Dongsung Kim *et al.*, "STUDY OF THE BEAM DIVERGENCE IN DIAMOND FIELD EMITTER ARRAY CATHODES" - Poster (8/14, Tue)
- Ryan Fleming *et al.*, "A Simple Variable Focus Lens For Field-Emitter Cathodes" - WG6 (8/16, Thurs)
- Chengkun Huang *et al.*, "EMISSION MODELS AND BEAM DYNAMICS FOR DIAMOND EMITTERS IN A COMPACT SOURCE OF HIGH BRIGHTNESS BEAMS" – WG5 (8/15, Wed)12

Supplement: Power Calibration of the Tunable UV Light Source



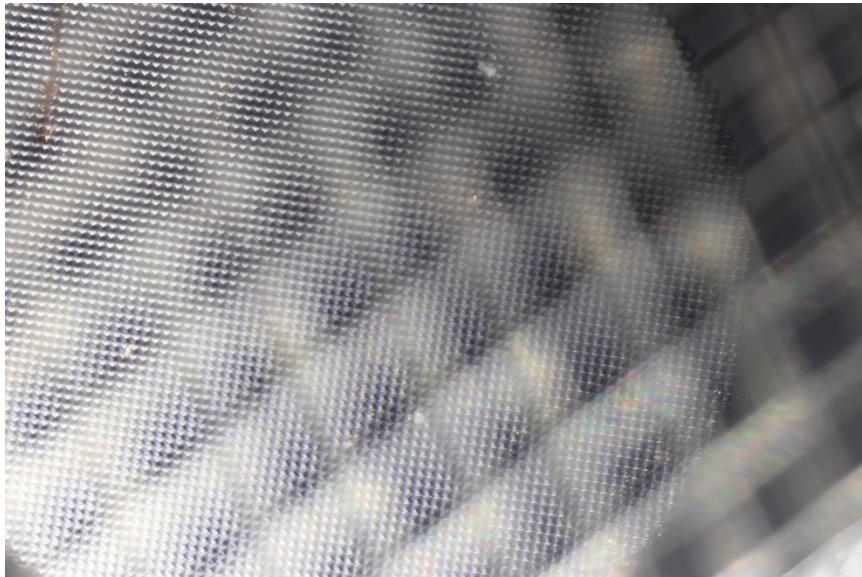
- Critical step for accurate quantum efficiency calculation
- Most of the “white” background is at 250+ nm, where diamond photocathodes are “blind”

Supplement: Anode-Cathode alignment

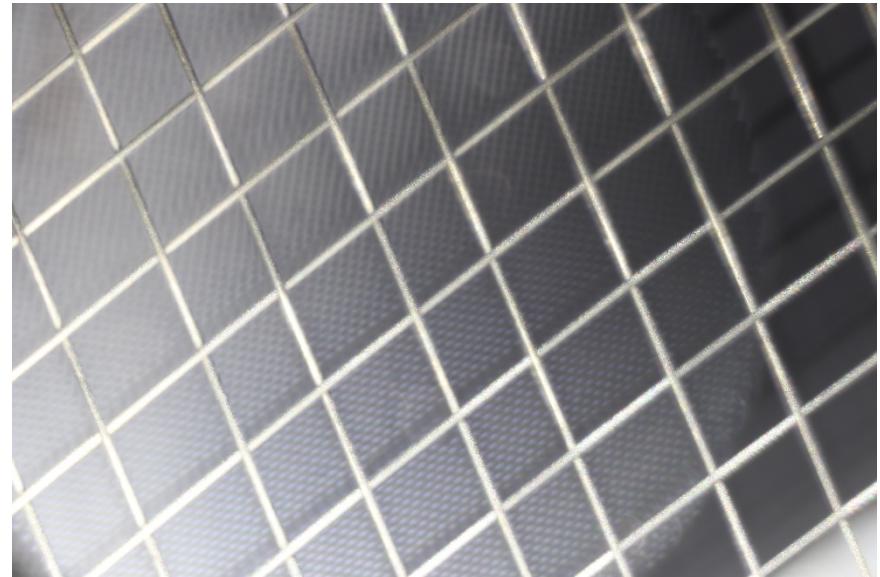


Supplement: Alignment of anode mesh vs sample plane

DFEA cathode approx. 250 μm behind anode mesh

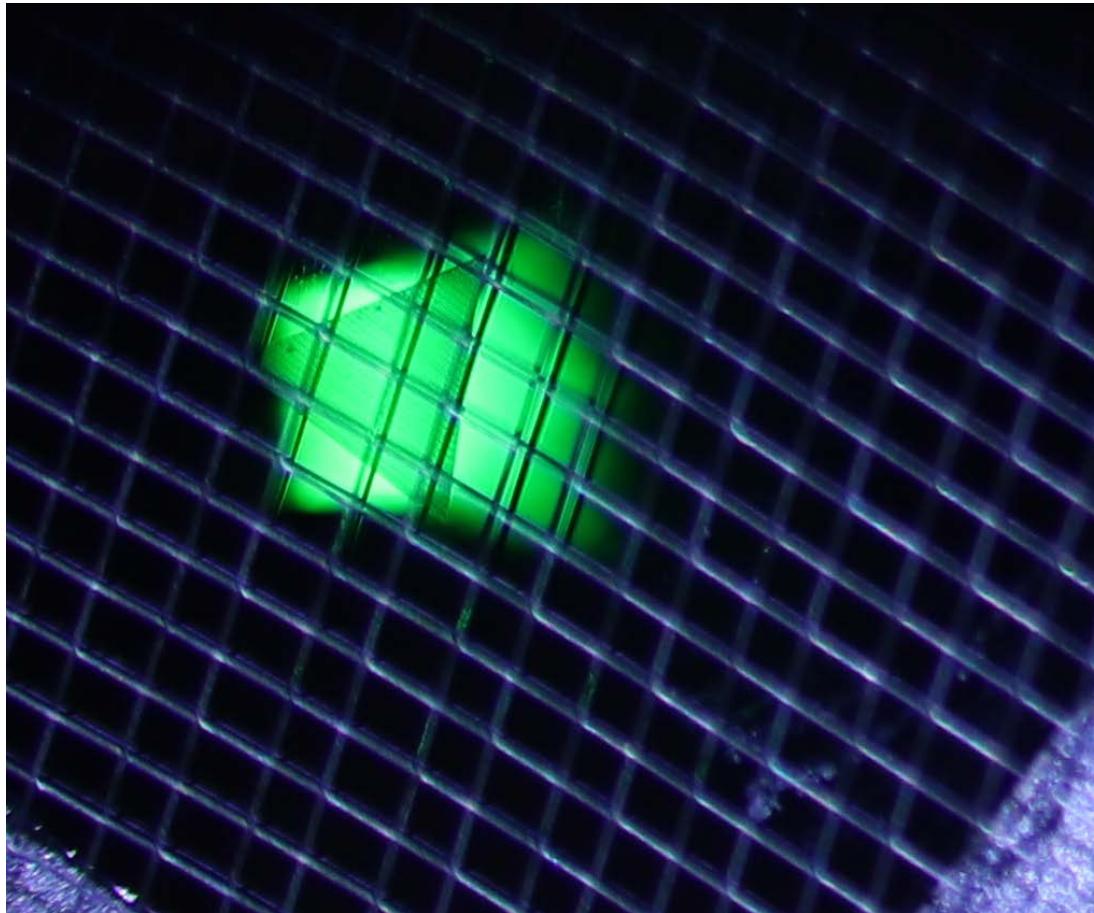


DFEA in focus



Anode mesh in focus

Supplement: Illumination Spot on DFEA pattern

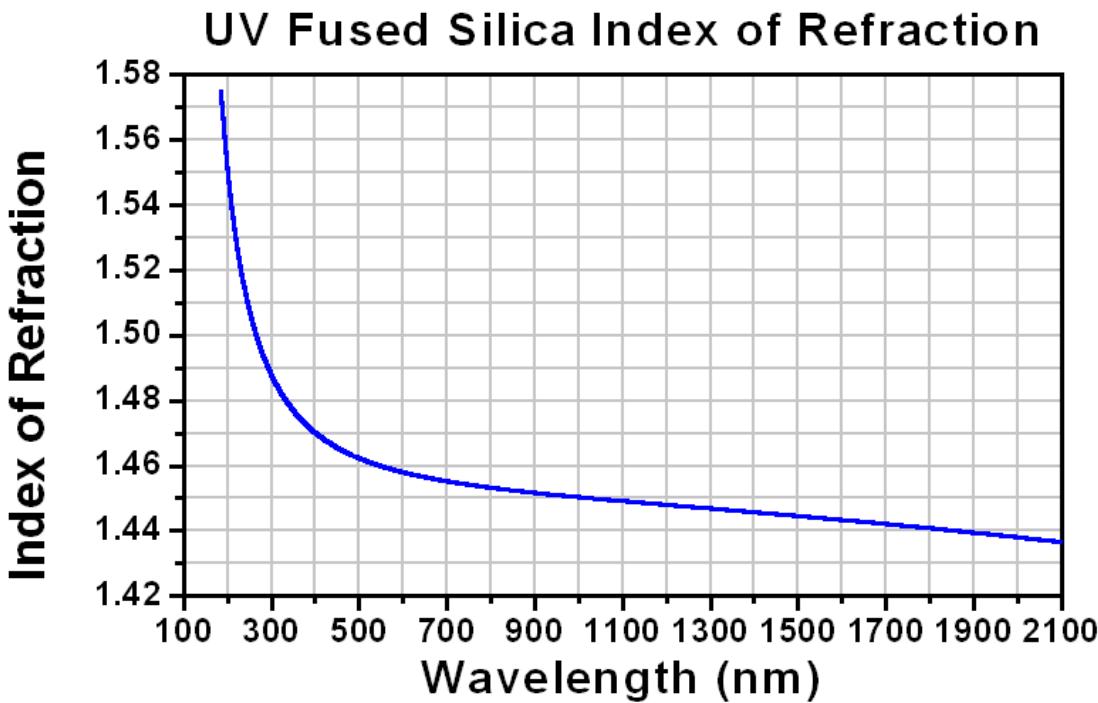


Output slit of
monochromator projected
onto DFEA patterned area

Supplement: Correction for 200 nm light

Lensmaker's Equation

$$\frac{1}{x_F} = (n - 1) \left(\frac{1}{x_{C_2}} - \frac{1}{x_{C_1}} \right)$$



75 mm FL lens will
perform
approximately as a
60 mm FL lens
around 200 nm